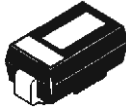
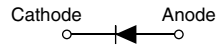


## Schottky Rectifier, 2.1 A



SMA



### FEATURES

- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Lead (Pb)-free ("PbF" suffix)
- Designed and qualified for industrial level


 Available  
**RoHS\***  
 COMPLIANT

### PRODUCT SUMMARY

$I_{F(AV)}$	2.1 A
$V_R$	100 V

### DESCRIPTION

The 10MQ100NPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

### MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	DC	2.1	A
$V_{RRM}$		100	V
$I_{FSM}$	$t_p = 5 \mu s$ sine	120	A
$V_F$	1.5 Apk, $T_J = 125^\circ C$	0.68	V
$T_J$	Range	- 55 to 150	$^\circ C$

### VOLTAGE RATINGS

PARAMETER	SYMBOL	10MQ100NPbF	UNITS
Maximum DC reverse voltage	$V_R$	100	V
Maximum working peak reverse voltage	$V_{RWM}$		

### ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current See fig. 4	$I_{F(AV)}$	50 % duty cycle at $T_L = 126^\circ C$ , rectangular waveform On PC board 9 mm <sup>2</sup> island (0.013 mm thick copper pad area)	1.5	A
Maximum peak one cycle non-repetitive surge current, $T_J = 25^\circ C$ See fig. 6	$I_{FSM}$	5 $\mu s$ sine or 3 $\mu s$ rect. pulse	120	A
		10 ms sine or 6 ms rect. pulse	30	
Non-repetitive avalanche energy	$E_{AS}$	$T_J = 25^\circ C$ , $I_{AS} = 0.5 A$ , $L = 8 mH$	1.0	mJ
Repetitive avalanche current	$I_{AR}$		0.5	A

\* Pb containing terminations are not RoHS compliant, exemptions may apply

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop See fig. 1	$V_{FM}^{(1)}$	1 A	$T_J = 25\text{ }^\circ\text{C}$	0.78	V
		1.5 A		0.85	
		1 A	$T_J = 125\text{ }^\circ\text{C}$	0.63	
		1.5 A		0.68	
Maximum reverse leakage current See fig. 2	$I_{RM}^{(1)}$	$T_J = 25\text{ }^\circ\text{C}$	$V_R = \text{Rated } V_R$	0.1	mA
		$T_J = 125\text{ }^\circ\text{C}$		1	
Threshold voltage	$V_{F(TO)}$	$T_J = T_J \text{ maximum}$		0.52	V
Forward slope resistance	$r_t$			78.4	m $\Omega$
Typical junction capacitance	$C_T$	$V_R = 10\text{ V}_{DC}$ , $T_J = 25\text{ }^\circ\text{C}$ , test signal = 1 MHz		38	pF
Typical series inductance	$L_S$	Measured lead to lead 5 mm from package body		2.0	nH
Maximum voltage rate of change	dV/dt	Rated $V_R$		10 000	V/ $\mu$ s

**Note**

(1) Pulse width < 300  $\mu$ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum junction and storage temperature range	$T_J^{(1)}$ , $T_{Stg}$			- 55 to 150	$^\circ\text{C}$
Maximum thermal resistance, junction to ambient	$R_{thJA}$	DC operation		80	$^\circ\text{C/W}$
Approximate weight				0.07	g
				0.002	oz.
Marking device		Case style SMA (similar D-64)		V1J	

**Note**

(1)  $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$  thermal runaway condition for a diode on its own heatsink

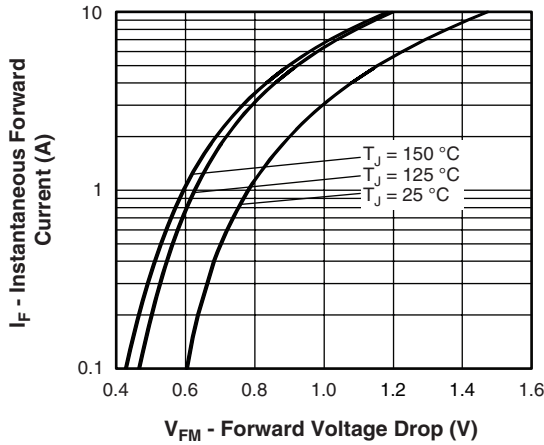


Fig. 1 - Maximum Forward Voltage Drop Characteristics

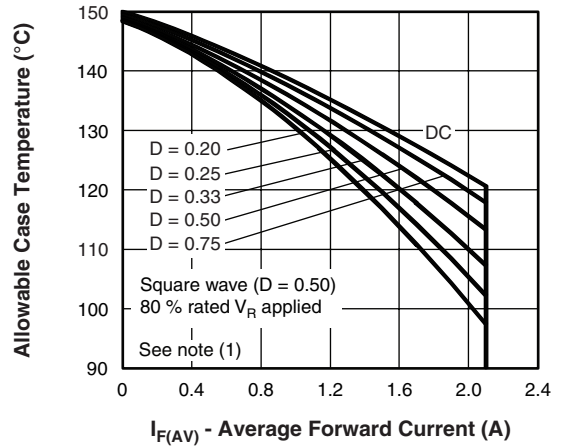


Fig. 4 - Maximum Average Forward Current vs. Allowable Lead Temperature

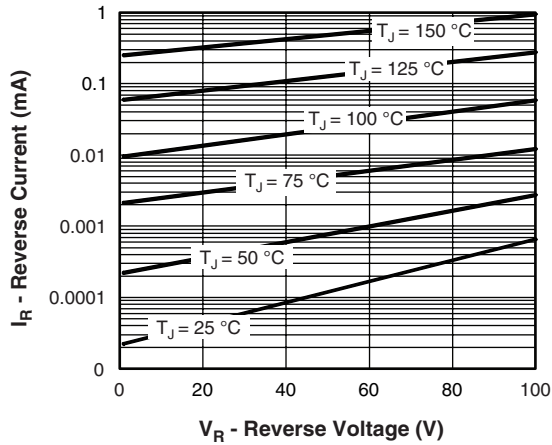


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

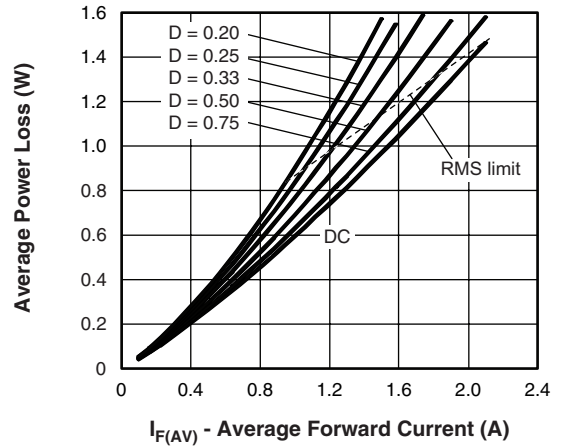


Fig. 5 - Maximum Average Forward Dissipation vs. Average Forward Current

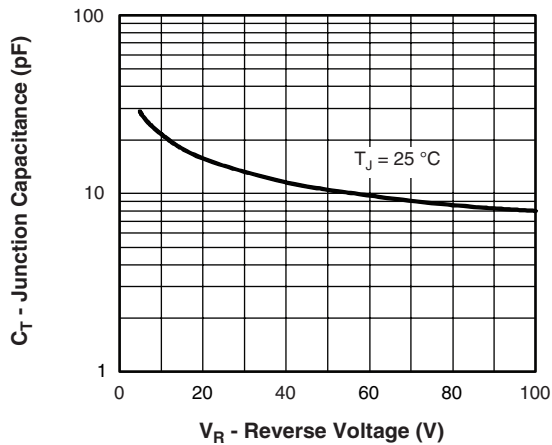


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

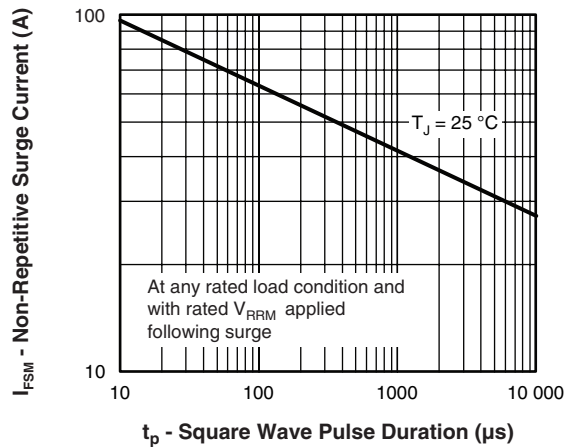


Fig. 6 - Maximum Peak Surge Forward Current vs. Pulse Duration

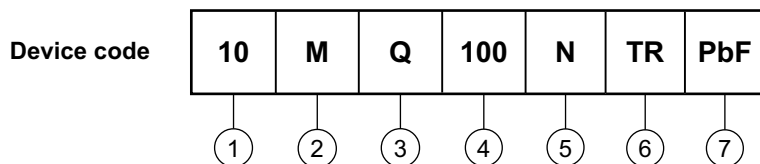
**Note**

(1) Formula used:  $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$ ;

$P_d$  = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);  $P_{d_{REV}}$  = Inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1} = 80\%$  rated  $V_R$



## ORDERING INFORMATION TABLE



- 1** - Current rating
- 2** - M = SMA
- 3** - Q = Schottky "Q" series
- 4** - Voltage rating (100 = 100 V)
- 5** - N = New SMA
- 6** -
  - None = Box (1000 pieces)
  - TR = Tape and reel (7500 pieces)
- 7** -
  - None = Standard production
  - PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS	
Dimensions	<a href="http://www.vishay.com/doc?95018">http://www.vishay.com/doc?95018</a>
Part marking information	<a href="http://www.vishay.com/doc?95029">http://www.vishay.com/doc?95029</a>
Packaging information	<a href="http://www.vishay.com/doc?95034">http://www.vishay.com/doc?95034</a>



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